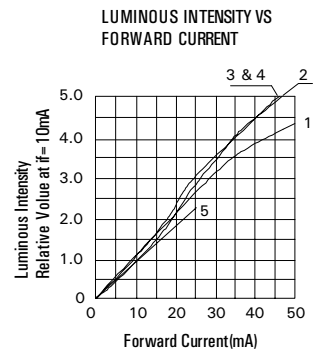
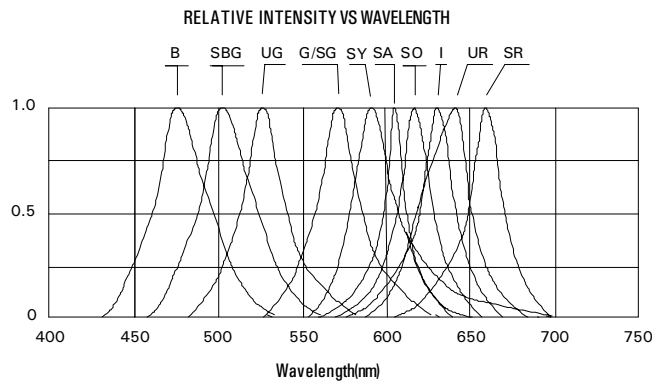
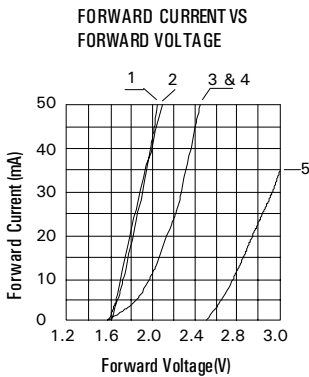


PART NO.	Common Anode	CA														
	Common Cathode	CC	KLA51 I	KLA51 SR	KLA51 G	KLA51 SG	KLA51 SY	KLA51 SA	KLA51 UR	KLA51 SO	KLA51 B/UB	KLA51 BG	KLA51 UG	KLA51 W		
			KLA52 I	KLA52 SR	KLA52 G	KLA52 SG	KLA52 SY	KLA52 SA	KLA52 UR	KLA52 SO	KLA52 B/UB	KLA52 BG	KLA52 UG	KLA52 W		
OPERATING CHARACTERISTICS AT 25°C (Bigger Display may have more than one LED chip per segment)			UNITS	SYMBOL	IRE D I	SUPER RED SR	GREEN G	SUPER GREEN SG	SUPER YELLOW SY	SUPER AMBER SA	ULTRA RED UR	SUPER ORANGE SO	BLUE B/UB	BLUE GREEN BG	ULTRA GREEN UG	WHITE W
Semiconductor Composition					AlGaAs		GaP/AlInGaP		AlInGaP			SiC / GaInN				
Forward Voltage - Typical @ 10mA			V	V_F	2.10	1.90	2.20	2.20	2.10	2.10	1.90	1.90	3.50	3.50	3.50	3.50
Forward Voltage - Maximum @ 20 mA			V	V_{FM}	2.40	2.10	2.60	2.40	2.40	2.40	2.10	2.40	4.50	4.50	4.50	4.50
Reverse Current @ $V_R = 5V$			μA	I_R	100	100	100	100	100	100	100	100	100	100	100	100
Peak Emission Wavelength			nm	λ_p	630	660	568	568	590	610	645	620	470	502	525	---
Emission Wavelength Half Width			nm	$\Delta\lambda$	35	20	30	15	15	15	20	20	25	30	35	---
Luminous Intensity per Segment			μcd	I_V	3500	6000	4000	6000	7000	7500	13000	13000	6000	7000	17000	---
ABSOLUTE MAXIMUM RATINGS AT 25°C																
Reverse Voltage			V	V_R	5	5	5	5	5	5	5	5	5	5	5	5
Forward Current (avg)			mA	I_F	20	20	20	20	20	20	20	20	20	20	20	20
Peak Forward Current ($T < 1\mu s$)			mA	I_{FS}	80	80	80	80	80	80	80	80	80	80	80	80
Operating / Storage Temperature Range			-10° C to +85° C													
Lead Soldering Temperature			< 260° C for 5 Seconds													
Series Resistor to be used per segment :			300 Ohms @ 5V Supply (OR) 50 to 100 Ohms @ 3V Supply													

ELECTRICAL CHARACTERISTIC CURVES



1. AlGaAs : I, SR

2. GaP : G

3 & 4. AlInGaP : SG, SY, SA, UR, SO

5. GaInN : B, BG, UG, W